

A Mess of Memory System Benchmarking, Simulation and Application Profiling

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Abstract—The Memory stress (Mess) framework provides a unified view of the memory system benchmarking, simulation and application profiling.

The *Mess benchmark* provides a holistic and detailed memory system characterization. It is based on hundreds of measurements that are represented as a family of bandwidth–latency curves. The benchmark increases the coverage of all the previous tools and leads to new findings in the behavior of the actual and simulated memory systems. We deploy the Mess benchmark to characterize Intel, AMD, IBM, Fujitsu, Amazon and NVIDIA servers with DDR4, DDR5, HBM2 and HBM2E memory. The *Mess memory simulator* uses bandwidth–latency concept for the memory performance simulation. We integrate Mess with widely-used CPUs simulators enabling modeling of all high-end memory technologies. The Mess simulator is fast, easy to integrate and it closely matches the actual system performance. By design, it enables a quick adoption of new memory technologies in hardware simulators. Finally, the *Mess application profiling* positions the application in the bandwidth–latency space of the target memory system. This information can be correlated with other application runtime activities and the source code, leading to a better overall understanding of the application’s behavior.

The current Mess benchmark release covers all major CPU and GPU ISAs, x86, ARM, Power, RISC-V, and NVIDIA’s PTX. We also release as open source the ZSim, gem5 and OpenPiton Metro-MPI integrated with the Mess memory simulator for DDR4, DDR5, Optane, HBM2, HBM2E and CXL memory expanders. The Mess application profiling is already integrated into a suite of production HPC performance analysis tools.

I. INTRODUCTION

The importance of the main memory in the overall system’s design [1]–[3] drives significant effort for memory system benchmarking, simulation, and memory-related application profiling. Although these three memory performance aspects are inherently interrelated, they are analyzed with distinct and decoupled tools. **Memory benchmarks** typically report the maximum sustainable memory bandwidth [4]–[6] or performance of the bandwidth-limited application kernels [7]. This is sometimes complemented with latency measurements in unloaded memory systems [8]–[10] or for a small number of memory-usage scenarios [11], [12]. **Memory simulators**

determine the memory system response time for a given traffic. Simple simulators model memory with a fixed latency, or calculate its service time based on queueing theory or simplified DDR protocols [13]–[19]. Dedicated cycle-accurate memory simulators consider detailed memory device sequences and timings [20]–[25]. **Application profiling tools** determine whether applications are memory bound based on the memory access latency [26]–[28], the position in the Roofline model [29], [30] or the the memory-related portion of the overall CPI stack [31].

Our study argues that the memory system benchmarking, simulation and application profiling can and should be based on a **unified view of memory system performance**. We provide this view with the **Memory stress (Mess) framework** comprised of the Mess benchmark, memory simulator and application profiling tool (Figure 1). **Mess benchmark** (Section II) describes the memory system performance with a **family of bandwidth–latency curves**. The benchmark covers the full range of the memory traffic intensity, from the unloaded to fully-saturated memory system. It also considers numerous compositions of read and write operations, plotted with different shades of blue in Figure 1 (middle). The Mess benchmark is designed for holistic and detailed memory system characterization that is easily adaptive to different target platforms. The current benchmark release covers all major CPU and GPU ISAs, **x86, ARM, Power, RISC-V**, and NVIDIA’s **Parallel Thread Execution (PTX)**, and it is applied to a number of actual hardware platforms and simulators.

We deploy the Mess benchmark to characterize **Intel, AMD, IBM, Fujitsu and Amazon servers** as well as **NVIDIA GPUs with DDR4, DDR5, HBM2 and HBM2E memory** (Section II-D). We report and discuss a wide range of memory system behavior even for the hardware platforms based on the same standard. These differences are especially pronounced in the high-bandwidth areas which have the greatest impact on memory-intensive applications. To the best of our knowledge, we are the first ones to detect and analyze the effect of **memory system over-saturation**, a scenario in which further increase of the memory request rate causes the system performance drop.

We also use the Mess benchmark to evaluate memory models of the widely-used hardware simulators: event-based **ZSim** [15], cycle-accurate **gem5** [16] and RTL simulator **OpenPiton Metro-MPI** [32] (Section II-E). Unfortunately, all tested memory simulators, including well-established and trusted gem5 DDR models and cycle-accurate memory simulators [22], [24], poorly resemble the actual system performance. The simulators show an unrealistically low load-to-use latency (starting at 4 ns), high memory bandwidth (exceeding $1.8\times$ the maximum theoretical one), and a simulation error of tens of percents for memory-intensive benchmarks, **STREAM** [5], **LMbench** [8] and Google Although it was not the initial design target, we also detected a case in which holistic and detailed Mess benchmarking diagnosed a CPU design error. In particular, Mess benchmarking of the OpenPiton measured an unexpected memory traffic, which led us to a bug in the coherency protocol generated by the OpenPiton framework.

Apart from the memory system characterization, the Mess bandwidth–latency curves can be also used for the memory performance simulation (Section III). We develop and integrate the **Mess memory simulator** in the **ZSim**, **gem5**, and **OpenPiton Metro-MPI simulators**, enabling simulation of high-end memory systems based on **DDR4**, **DDR5**, **Optane**, **HBM2**, and **HBM2E** technologies, and **Compute Express Link (CXL)** [33]. The Mess integration is easy, based on the standard interfaces in the CPU simulators that enable external memory simulation [15], [16], [34]. The Mess simulator closely matches the actual memory systems performance. The simulation error for memory-intensive **STREAM**, **LMbench** and Google multichase is between 0.4% and 6%, which is significantly better than all other memory models we tested. Mess is also fast. For example, Mess integrated with **ZSim** introduces only 26% simulation time increment over the fixed-latency memory model, while the speed-up over the **Ramulator** and **DRAMsim3** ranges between $13\times$ and $15\times$. Another advantage of the Mess simulator is that it removes the current lag between the emergence of memory technologies and development of the reliable simulation models. For example, Mess is the first memory simulator that models **CXL memory expanders**, enabling further research on these novel memory devices. The simulation is based on the bandwidth–latency curves obtained from Micron Technology’s SystemC hardware model (Section III-C).

Finally, the Mess memory bandwidth–latency curves enhance application profiling and performance analysis (Section IV). **Mess application profiling** determine positions of application execution time segments on the corresponding memory bandwidth–latency curves. The application memory stress can be combined with the overall application timeline analysis and can be linked to the source code. The Mess application profiling is already integrated into a suite of **production HPC performance analysis tools** [35].

The inherent dependency between the used memory bandwidth and the access latency is by no means a new phenomenon, and the community has known about it at least for a couple of decades [36]. The Mess framework extends the previous work

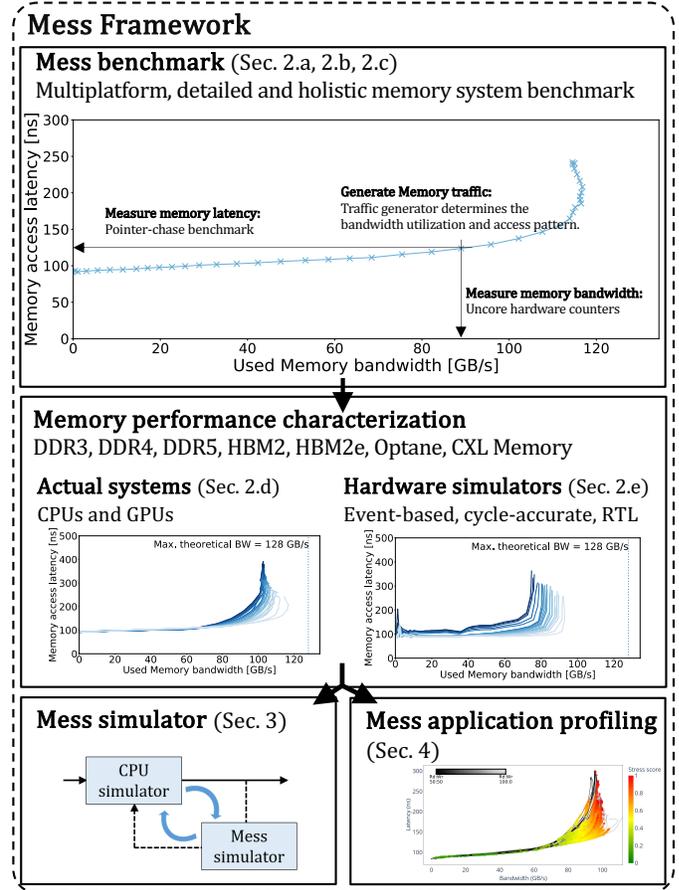


Fig. 1. Mess framework: The Mess benchmark describes the memory system performance with a family of bandwidth–latency curves. We deploy the benchmark to characterize memory systems of actual servers and hardware simulators. The Mess bandwidth–latency curves can be also used for the memory performance simulation and memory-related application profiling.

in three important aspects. Previous studies typically use a single bandwidth–latency memory curve to illustrate a **general memory system behavior** [12], [27], [36]–[39]. The Mess benchmark is designed for **holistic, precise and close-to-the-hardware** memory system performance characterization. To reach this objective, the Mess benchmark is developed directly in the assembly, and the experiments are tailored to minimize and mitigate the impact of the system software. Mess benchmark performs a **detailed characterization of the particular system under study**. It detects and quantifies some aspects of the memory systems behavior not discussed in previous studies, such as the impact of the read and write memory traffic on performance, or discrepancies between different memory systems, both in actual platforms and hardware simulators. Second, the Mess framework **tightly integrates the memory performance characterization into the memory simulation**. The Mess simulator avoids complex memory system simulation and simply adjusts the rate of memory instructions (provided by the CPU simulator) to the actual memory performance. The accuracy of this simulation approach relies on the input memory performance characterization. This characterization

therefore has to be holistic, detailed and specific to the system under study, closely matching the Mess benchmark design. Third, the framework **closely couples the memory-related profiling of hardware platforms and applications**. Similar to the Mess simulator, the Mess application profiling itself is uncomplicated, and its real value comes from the application analysis in the context of the memory system characteristic. The quality of the memory characterization therefore directly impacts the the quality of the overall analysis. For this reason, the analysis cannot be performed with generic bandwidth–latency approximations, but it requires detailed Mess-like memory performance description.

The Mess benchmark is released as open source and it is ready to be used in **x86, Power, ARM, and RISC-V** CPUs and **NVIDIA** GPUs. The release also contains all bandwidth–latency measurements shown in the paper, including the **CXL expander curves** provided by Micron Technology. We also release as open source the **ZSim, gem5 and OpenPiton Metro-MPI** integrated with the Mess memory simulator supporting **DDR4, DDR5, Optane, HBM2, HBM2E and CXL expanders**. Also, the public releases of the **production HPC performance analysis tools** already include the Mess application profiling extension. The released tools are ready to be used by the community for better understanding of the current and exploration of future memory systems.

II. MESS BENCHMARK

This section describes the Mess benchmark use, and analyzes its characterization of actual platforms and hardware simulators.

A. Mess benchmark: Memory bandwidth–latency curves

The Mess memory characterization comprises tens of bandwidth–latency curves, each corresponding to a specific ratio between the read and write memory traffic. The Mess benchmark kernels cover the whole range of memory operations, from 100%-loads to 100%-stores. The 100%-load kernel generates a 100%-read memory traffic, while the 100%-store kernel creates 50%-read/50%-write traffic. This is because the contemporary CPUs deploy the write-allocate cache policy [40]. With this policy, each store instruction first reads data from the main memory to the cache, then modifies it, and finally writes it to the main memory once the cache line is evicted. Each store instruction, therefore, does not correspond to a single memory write, but to one read and one write.¹

The Mess bandwidth–latency curves are illustrated in Figure 1 (middle). The curves with different composition of read and write traffic are plotted with different shades of blue. Each curve is constructed based on tens of measurement points that cover the whole range of memory-traffic intensity. Figure 1 (top) illustrates the construction process for one of

¹Memory traffic with more than 50% of writes can be generated with non-temporal (streaming) stores that directly store data in the main memory. These instructions, however, are not supported in all HPC platforms. Even when supported, they are seldom used. In SPEC CPU2006 [41], SPEC CPU2017 [42], and SPLASH-2 [43] benchmarks running on the Intel Skylake server with Intel Pin tool [44], the non-temporal stores correspond to <1% of the overall memory instructions.

the curves. The memory access latency is measured with a pointer-chase benchmark [45], [46] executed on one CPU core or one GPU Stream Multiprocessor (SM). This determines the y -axis position of the measurement. The x -axis corresponds to memory bandwidth, monitored with hardware counters [47]–[50]. Running pointer-chase alone measures the unloaded memory access latency. To measure the latency of the loaded memory system, concurrently with the pointer-chase, on the remaining CPU cores or GPU SMs, we run a memory traffic generator. The traffic generator is designed to create a wide range of memory traffic with configurable memory bandwidth utilization and read/write ratio. Both, pointer-chase and traffic generator are implemented in assembly to minimize any compiler intervention. The detailed implementations of pointer-chase and traffic generator is presented in Appendix A. To minimize the latency penalties introduced by the TLB misses and the page walk, the Mess data-structures are allocated in huge memory pages. Additionally, at runtime, these overheads are monitored with hardware counters and subtracted from the memory latency measurements. The Mess benchmark release includes the source code and its detailed description, as well as the instructions for the benchmark compilation and execution.

B. Validation

The Mess benchmark provides a holistic and detailed memory characterization exceeding all existing benchmarks and tools. Still, these tools can validate some of the Mess measurements.

The unloaded memory system latency can be measured with LMBench and Google multichase in CPU platforms, and P-chase [51] in GPUs. We used these benchmarks to validate the Mess unloaded latency measurements in all hardware platforms under study, see Table I. In all experiments, Mess closely matches the LMBench, Google multichase and P-chase results.

In Intel systems, the maximum sustained memory bandwidth can be measured with the Intel Advisor [4]. In the Skylake, Cascade Lake and Sapphire Rapids servers under study, the Mess benchmark matches the Advisor measurements, with a difference below 1%.

The Intel Memory Latency Checker (MLC) [11], can measure the memory latency for a selected memory traffic intensity, i.e. memory bandwidth. The memory bandwidth can be fine-tuned, but the tool provides a sparse analysis of different traffic compositions, i.e. read and write memory operations. We compare the Intel MLC results and the corresponding subset of the Mess measurements for all Intel platforms under study. The MLC and Mess results show the same trend, with slightly lower (<5%) latencies reported by the Mess benchmark. This is because the Mess is designed for close-to-the-hardware memory characterization, so it excludes the latency penalties introduced by the OS overheads, the TLB misses and the page walk.

C. Performance analysis

Figure 2 illustrates the Mess benchmark performance analysis with an example of the 24-core Intel Skylake server with six DDR4-2666 memory channels [52]. The figure

confirms a general trend of the memory access latency which is initially roughly constant and then increases with higher memory pressure (i.e. bandwidth) due to resource contention among parallel accesses [36], [53], [54].

Detailed and close-to-the-hardware Mess characterization reveals some memory system aspects not discussed by previous studies. The most important one is the impact of the read and write memory traffic. The best performance, the lowest latency and the highest achieved bandwidth, are obtained for 100%-read traffic. Memory writes reduce the memory performance and reach the saturation point sooner. This is due to the extra timing constraints such as t_{WR} and t_{WTR} , which come with memory write operations [55]. We detect this behavior for all the Intel, AMD, IBM, Fujitsu, and Amazon servers as well as NVIDIA GPUs used in the study with DDR4, DDR5, HBM2 and HBM2E memory (Section II-D). However, we see a very different write traffic impact on CXL memory expanders [33]. We analyze this behavior of CXL memory expanders in Section III-C.

Apart from the memory bandwidth–latency curves, we use the Mess benchmark to derive memory system performance metrics, also depicted in Figure 2, for quantitative comparison of different memory systems. In addition to the commonly-used unloaded memory latency, the detailed Mess characterization quantifies the **maximum latency range** of memory access latencies for all read-to-write ratios and the **saturated bandwidth range**. The memory system is saturated when any further increase in the memory system pressure, i.e. bandwidth, leads to a high increase in the memory access latency. We consider that the saturated bandwidth area starts at the point in which the memory access latency doubles the unloaded latency. In some of the platforms under study, we also detect a **memory system over-saturation**. Any increase in the memory system pressure after the over-saturation point causes a decline in the used memory bandwidth, while the access latency continues to increase. This behavior is observed in the bandwidth–latency curves as a “wave form” seen in Figure 2. The causes for this memory behavior are analyzed in Section II-D. To the best of our knowledge, our study is the first one to detect and analyze this suboptimal memory system behavior.

Although STREAM is the *de facto* standard for measuring sustained memory bandwidth [5], [56], Figure 2 shows significant gap between the **STREAM bandwidth** and the maximum measurements of the Mess benchmark. The sources of this gap are analyzed in the next section.

D. Performance characterization: Actual systems

We use the Mess measurements to compare the memory system performance of Intel, AMD, IBM, Fujitsu and Amazon servers as well as NVIDIA GPUs with DDR4, DDR5, HBM2 and HBM2E. The platform and memory system characteristics are listed in Table I while Figure 3 shows their bandwidth–latency curves. The **unloaded memory latency** varies significantly between different platforms. It ranges from 85 ns in the Cascade Lake server with DDR4, to 122 ns in the A64FX servers with HBM2 and 129 ns in the Graviton 3

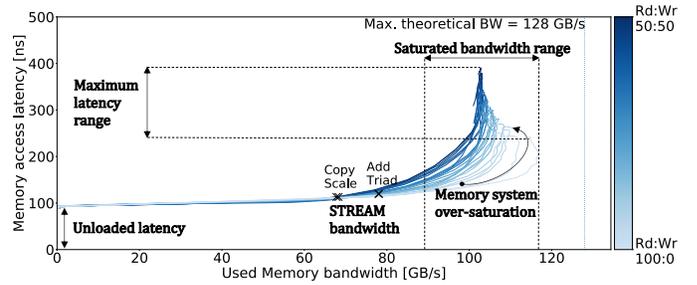


Fig. 2. The Mess benchmark models the memory system performance with a family of bandwidth–latency curves. It covers the whole feasible read/write ratio of memory operations, and the whole space of the traffic intensity, from unloaded to fully-saturated memory systems.

with DDR5 main memory. This difference should not be directly associated to the memory technology and standard. For example, the AMD Zen2 comprises DDR4 technology with practically the same command latencies (in nanoseconds) as the Intel Cascade Lake server, and still it shows almost 30 ns higher unloaded memory latency. This is because the load-to-use latency considers the time memory requests spend within the CPU chip, including the cache hierarchy and network on chip. These timings can differ significantly between different CPU architectures independently of the target memory system. Actually, we detect the highest unloaded memory latencies in the chips with the largest number of cores (Zen2, A64FX, Graviton 3) indicating that at least a portion of this latency is likely to be attributed to the network on chip which is larger and more complex in these architectures. NVIDIA H100 GPU shows higher unloaded latency due to its massive number of arithmetic processing units, lower on-chip frequency, and complex memory hierarchy [51], [63].

We also detect a wide **maximum latency range** between different platforms, and even within a single platform for different read and write memory traffic. Maximum memory latency is a primary concern in real-time systems, and it is less critical in high-performance computing (HPC). Still it has to be bound to guarantee quality of service of some HPC applications. We believe that our study may open a discussion about the sources of different maximum latencies in different systems, e.g. due to the different lengths of the memory queues, and about its desirable limits.

All platforms except AMD Zen2 CPU and NVIDIA H100 show a similar **saturated bandwidth range**, between approximately 70% and 90% of the maximum theoretical bandwidth. The maximum achieved bandwidth cannot reach the theoretical one because part of it is “lost” due to factors such as DRAM refresh cycles blocking the entire chip, page misses causing precharge and activate cycles, and timing restrictions at the bank, rank, and channel levels [64]. The efficiency of the memory bandwidth utilization also depends on the memory controller design. As expected (see Section II-C), the best utilization is achieved for 100%-read memory traffic, and it reduces with the increment of the memory writes. AMD Zen2 is an exception in two ways. First, its saturated bandwidth range

TABLE I
CPU AND GPU PLATFORMS UNDER STUDY: QUANTITATIVE MEMORY PERFORMANCE COMPARISON.

Platform	Intel Skylake Xeon Platinum [52]	Intel Cascade Lake Xeon Gold [52]	AMD Zen 2 EPYC 7742 [57]	IBM Power9 02CY415 [58]	Amazon Graviton 3 [59]	Intel Sapphire Rapids Xeon Platinum [60]	Fujitsu A64FX [61]	NVIDIA Hopper H100 [62]
Released	2015	2019	2019	2017	2022	2023	2019	2023
Cores @ frequency	24 @ 2.1 GHz	16 @ 2.3 GHz	64 @ 2.25 GHz	20 @ 2.4 GHz	64 @ 2.6 GHz	56 @ 2GHz	48 @ 2.2 GHz	132 SMs @ 1.1 GHz
Main memory	6×DDR4-2666	6×DDR4-2666	8×DDR4-3200	8×DDR4-2666	8×DDR5-4800	8×DDR5-4800	4×HBM2	4×HBM2E
Theoretical bandwidth	128 GB/s	128 GB/s	204 GB/s	170 GB/s	307 GB/s	307 GB/s	1024 GB/s	1631 GB/s
<i>% of the max theoretical bandwidth</i>								
Saturated bandwidth range	72–91%	68–87%	57–71%	67–91%	63–95%	60–86%	72–92%	51–95%
Stream kernels	53–61%	51–57%	46–51%	32–36%	78–82%	63–66%	49–55%	64–69%
Unloaded latency	89 ns	85 ns	113 ns	96 ns	122 ns	109 ns	129 ns	363 ns
Maximum latency range	242–391 ns	182–303 ns	257–657 ns	238–546 ns	332–527 ns	238–406 ns	338–428 ns	699–1433 ns

is significantly lower, 57–71% of the maximum theoretical one. Second, it does not follow the expected impact of the write traffic on the bandwidth utilization. Instead, the traffic with the maximum rate of memory writes shows a very good performance, very close to the 100%-read traffic, while the main drop is detected for a mixed, e.g. 60%-read/40%-write, traffic.

We detect the **memory system over-saturation**, in some AMD Zen 2, Intel Skylake and Intel Cascade Lake bandwidth–latency curves. In Amazon Graviton 3, Intel Sapphire Rapids and NVIDIA H100 the over-saturation is frequent for the memory traffic with high percent of writes.² We explored this behavior in the Cascade Lake servers in which we had access to additional memory system counters, e.g. monitoring the row-buffer statistics. In all the memory over-saturation experiments we detect a significant increase in row-buffer misses. In case of a row-buffer miss, the current content of the row is stored in the memory array and the correct row is loaded into the row-buffer. These additional operations increase the memory access time and reduce the effective device bandwidth, matching the over-saturated memory behavior. To confirm these findings, we increased the memory system pressure by removing four out of six DIMMs in each socket. In these experiments, we detected a large over-saturation areas in all bandwidth–latency curves. And indeed, the measurement confirmed that the over-saturation is highly correlated with the row-buffer miss rate.

Finally, we detect that in most of the platforms the bandwidths reported by the **STREAM** kernels are significantly below the Mess measurements.^{3,4} In the Intel and A64FX platforms, the STREAM reports around half of the maximum theoretical bandwidth. In IBM Power9, the STREAM reports only one third of it. There are two main sources of this gap. The first one is that the STREAM does not measure, but *estimates* the memory bandwidth. This estimate is based on

²These findings are consistent with two recent studies which report that running high-bandwidth benchmarks on all CPU cores may lead to lower memory bandwidths w.r.t. the experiment in which some cores are not used [6], [65].

³The STREAM benchmark measures the performance of four kernels: Copy, Scale, Add and Triad. All the results presented in this study follow the Stream guidelines: they are obtained with the C version of the benchmark running with 64-bit data types with no significantly modified code or assembly language [66].

⁴In Graviton 3 and NVIDIA H100, the results reported by STREAM are very close to the maximum Mess measurements for the corresponding read/write ratio. This would correspond to a architecture with a write-through cache policy. We did not find any public document that details this aspect of the Graviton 3 and NVIDIA H100 cache organization.

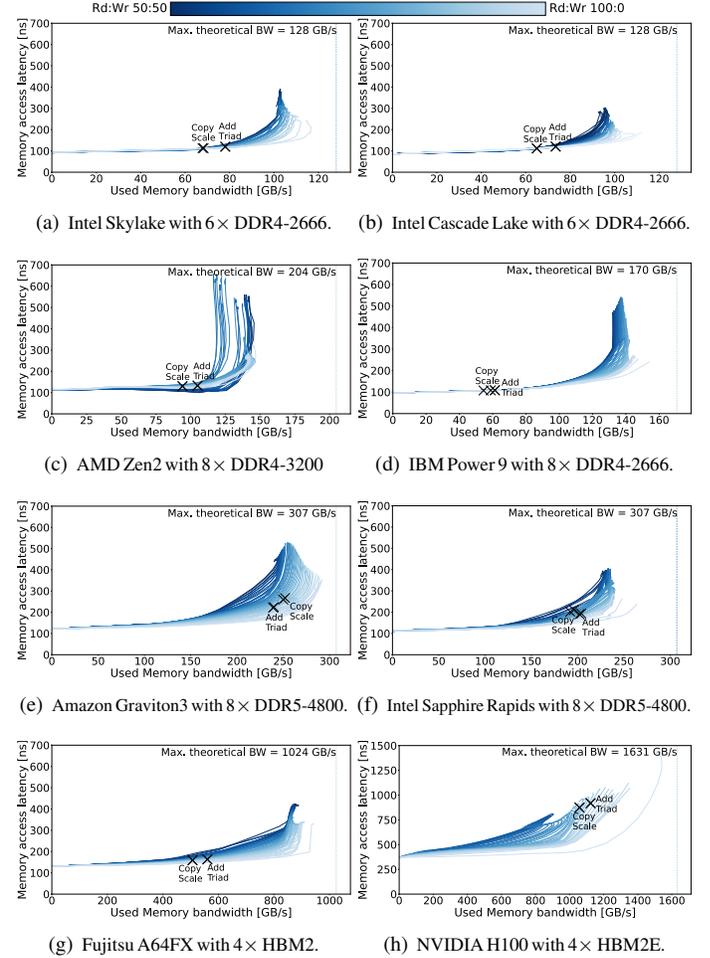


Fig. 3. We detect a wide range of memory system behavior, even for the hardware platforms with the same memory standard.

the application execution time, size of the data structures used in the computation, and number of load and store instruction in each STREAM kernel. In particular, STREAM calculation assumes one memory read for each load instruction and one memory write for each store. This is not the case in most of the state-of-the-art HPC servers because they deploy a write-allocate cache policy. Each store instruction, therefore, does not correspond to a single memory write, as assumed in the STREAM bandwidth calculation, but to one read and one write (see Section II-A). The second cause of the gap between

the Mess and STREAM bandwidth is the composition of the memory traffic. The Mess benchmark achieves the maximum bandwidth for a 100%-read traffic. The write memory traffic, present in all STREAM kernels, adds timing constraints and reaches sooner the bandwidth saturation point.

E. Performance characterization: Memory simulators

Mess benchmark can also be used to characterize memory simulators and compare them with the actual systems they intend to model. We illustrate this Mess capability with the gem5, ZSim, and OpenPiton Metro-MPI simulators with different internal memory models and widely-used external memory simulators, DRAMsim3 and Ramulator.

1) *gem5*: The gem5 [16] is a cycle-accurate full-system simulator. In our experiments, the simulator is configured to model the Graviton 3 server with 64 Neoverse N1 cores [59]. The cache hierarchy includes 64 KB of 4-way L1 instruction and data cache, 1 MB of 8-way private L2 cache and 64 MB of 16-way shared L3. The main memory system has eight eight DDR5-4800 memory channels. Figure 4 compares Mess bandwidth–latency curves of the actual server with gem5 internal memory models: simple memory model and internal DDR model. To maintain a reasonable simulation time, we model each system with a family of six curves, from 50% to 100% read memory traffic with a 10% step.

Practically in the whole bandwidth range, the gem5 **simple memory model** delivers a fixed latency of 4–49 ns. The latency increases only when the bandwidth asymptotically approaches its theoretical maximum. Contrary to the Graviton 3 server, the highest latencies are measured for a 100%-read traffic, and the latency drops with the percent of memory writes. Also, unlike in the actual platform, for some memory traffic increasing the bandwidth reduces the memory access latency. For example, the 50%-read/50%-write traffic reaches the lowest simulated latency of only 4 ns at the 200 GB/s bandwidth. The same traffic in the actual system has the memory access latency of 261 ns.

The more detailed **internal DDR model** shows small improvements over the simple memory model, but still poorly resembles the actual system behavior. The simulated latencies are unrealistically low, most of them in the range of 14–100 ns. Similarly to the gem5 simple memory model, the latencies drops with the percent of memory writes. For all the curves except 100%-read, the saturated bandwidth is significantly lower from the one measured on the actual system. Again, the error increases with the percent of memory writes.

2) *ZSim*: We select ZSim [15] as a representative of event-based hardware simulators. We use publicly-available ZSim modeling 24-core Intel Skylake processor connected to six DDR4-2666 channels [67]. The cache hierarchy of the modeled CPU includes 64 KB of 8-way L1 instruction and data cache, 1 MB of 16-way private L2 cache and 33 MB of 11-way shared L3. The simulator is extensively evaluated against the actual hardware platform [68]. The ZSim comprises three internal memory models: fixed-latency, M/D/1 queue model and the internal DDR model. Also it is already connected to Ramulator [24], [69] and DRAMsim3 [22]. To avoid any error due

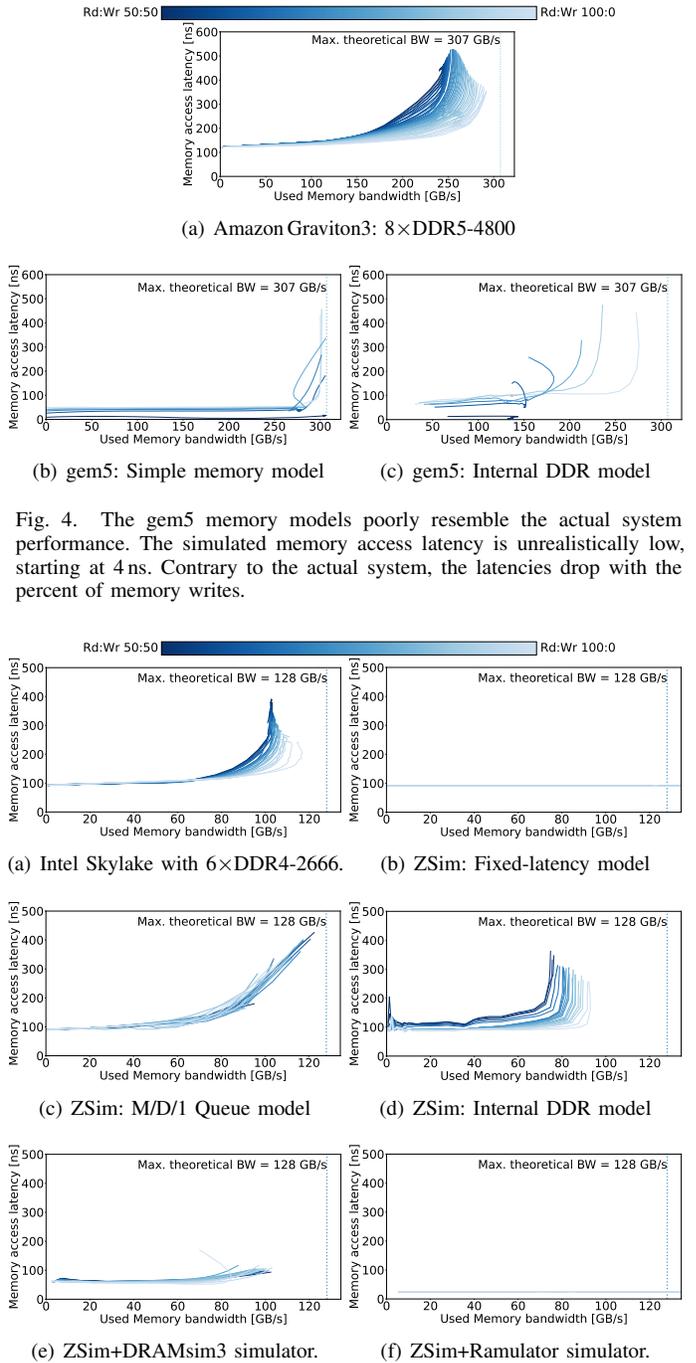


Fig. 4. The gem5 memory models poorly resemble the actual system performance. The simulated memory access latency is unrealistically low, starting at 4 ns. Contrary to the actual system, the latencies drop with the percent of memory writes.

Fig. 5. Memory system performance of the actual Intel Skylake server and various ZSim memory models.

to the integration of an event-based CPU simulator with cycle-accurate memory models [46], [70], [71], we use the ZSim interfaces included in the Ramulator and DRAMsim3 releases.

We compare the Mess bandwidth–latency curves of the actual server with all five ZSim approaches for the main memory simulation (see Figure 5). We configure the fixed-latency model with the unloaded memory latency measured in the actual system. The M/D/1 queue model also requires user to specify the maximum theoretical bandwidth, which is 128 GB/s in the

platform under study. The internal DDR model, Ramulator and DRAMsim3 are based on the detailed simulation of the DDR4-2666.

As expected, the **fixed-latency memory model** provides a constant latency in the whole bandwidth domain. Given that this latency is configured by a user, it can be set to match the unloaded memory latency in the actual system. On the down side, the memory bandwidth provided by this model is unrealistic: the maximum simulated bandwidth is 342 GB/s, which exceeds the maximum theoretical one by $2.7\times$. The **M/D/1 queues** correctly model the memory system behavior in the linear part of the curves. The modeling of the system saturation is less accurate. The queue model does show some difference between read and write memory traffic, but the reported performance does not correspond to the actual system trend in which increasing the write traffic lowers the performance. The **internal DDR model** shows the closest performance match to the actual system — it models the linear and saturated segments of the curves, and the impact of the memory writes. Still, there are three main difference w.r.t. to the actual system. First, the simulator underestimates the saturated bandwidth area to 69–93 GB/s, significantly below the 92–116 GB/s measured in the actual system. Second, the simulator excessively penalizes the memory writes which is seen as a wider spread of the curves with a higher write memory traffic. Third, we detect some unrealistic memory-latency peaks in the low-bandwidth 1–4 GB/s curve segments. The **DRAMsim3** shows a similar trend as the M/D/1 queue model in the linear segments of the memory curves, with some latency error, 52–63 ns in the DRAMsim3 versus 89–109 ns in the actual system. The simulator does not model the saturated bandwidth area. Finally, the **Ramulator** provides a fixed 25 ns latency in the whole bandwidth area and for all memory traffic configurations. Also, similar to the fixed-latency model, the simulated bandwidth is unrealistic, exceeding by $1.8\times$ the maximum theoretical one.

Our evaluation of the memory models and detailed hardware simulators detected major differences w.r.t. the actual memory systems performance. DRAMsim3 and Ramulator, which rely on detailed memory models, are considered *de facto* standard for the memory system simulation. Also, both of them are evaluated against the manufacturer’s Verilog implementations and they show no violation of the JEDEC timings [55]. However, as our results demonstrate, this does not guarantee that the simulators properly model the full system performance.

3) *RTL simulators: OpenPiton and Metro-MPI:* OpenPiton framework [72] provides an open-source RTL implementation of a tiled architecture based on Ariane RISC-V cores [73]–[75]. Developed in the Verilog RTL, the OpenPiton simulation is slow, especially for large number of cores. We use the OpenPiton simulation accelerated by Metro-MPI [32]. This approach uses Verilator [76] to convert the RTL code of each tile into a cycle-accurate C++ simulation model. Then, all the tiles are simulated in parallel and their interconnect communication is done with the MPI programming interface.

In our experiments, the OpenPiton framework is configured

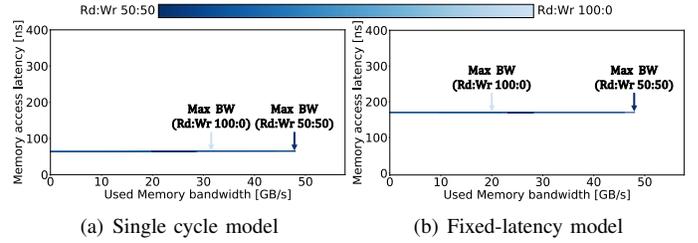


Fig. 6. Memory system performance of the OpenPiton Metro-MPI simulator.

to generate 64-core Ariane architecture which includes 16 KB of 4-way L1 instruction and data cache, and 4 MB of 4-way shared L2 cache. The main memory is originally modeled with a single-cycle latency, and it is recently extended with a fixed-latency model [74]. We set this latency to 170 ns. Our Mess measurements, see Figure 6, confirm that both models deliver the expected load-to-use latency. Also, as expected, we see no difference between read and write memory traffic, leading to a perfect overlap of the curves. The only difference is in the maximum observed memory bandwidth. For a single-cycle memory latency, 100%-read memory traffic achieves 32 GB/s, limited by the memory concurrency of the 64 in-order Ariane cores. Memory writes do not stall the cores, so the achieved memory bandwidth increases with the write memory traffic ratio. Still, a small 2-entry miss status holding registers (MSHR) limits the memory bandwidth to 47 GB/s for 50%-read/50%-write traffic. We detect the same trend for the fixed memory model.

The Mess evaluation of the OpenPiton Metro-MPI resulted in an unexpected discovery: in some experiments we detected significantly higher memory write traffic than anticipated. By analysis of the system behavior for various Mess configurations, we connected the extra memory traffic to the unnecessary eviction of the data from the last-level cache. Instead of evicting only the dirty cache lines, the system was evicting all of them. The source of the error is the coherency protocol generated by the OpenPiton framework. The error is reported to the OpenPiton developers and they confirmed its existence. Although not part of the original plan, our exploration discovered that holistic and detailed Mess performance characterization can be also used to uncover CPU design errors.

III. MESS SIMULATOR

In this section we will present the Mess memory simulator and show how it significantly improves the memory simulation accuracy.

A. Design

The CPU and memory simulators are typically connected in the following way: the CPU simulator issues the memory operations and the memory simulator determines their latencies. The Mess simulator does this based on the application’s position in the memory bandwidth–latency curves. This process is complex due to the inherent dependency between the memory system latency, timings of the memory operations

and all dependent instructions, and the generated memory bandwidth. We simplify the problem by designing the Mess simulator not to compute the exact memory latency for a given memory traffic, but to detect and correct discrepancies between the memory access latency and the simulated bandwidth. This approach, together with the fundamental principle of application’s position in the memory bandwidth–latency curves, enables the Mess simulator to surpass the accuracy of all other memory simulators, while remaining simple and fast.

The Mess simulator acts as a feedback controller [77] from the classical control theory [78], illustrated in Figure 7. The CPU simulation can start from any memory access latency, e.g. the unloaded one. The feedback control loop monitors the simulated bandwidth and controls whether it correspond to the memory latency used in the CPU simulation. If this is not the case, the memory latency is being adjusted with an iterative process we describe later. The control process is performed at the end of each simulation window, which, in our experiments, comprises 1000 memory operations. This is much smaller than the length of the application phases [64], so the error due to the transition between different application phases has a negligible impact on the simulator’s accuracy.

Figure 8 describes one iteration of the Mess simulator control loop. We start with the Mess estimate of the application’s bandwidth–latency position in the i^{th} simulation window, $(messBW_i, Latency_i)$ ❶. From that point on, all the issued memory requests are simulated with $Latency_i$. At the end of the simulation window, based on the outcomes of the CPU simulation, the Mess simulator monitors the simulated memory bandwidth, $cpuBW_i$ ❷, and compares it with the $messBW_i$ estimated at the beginning of the window ❸.

If the simulation is in a steady-state and the application did not change its behavior, there will be no major difference between $cpuBW_i$ and $messBW_i$. This confirms the consistency in the simulated memory access latency, the CPU timings and the achieved memory bandwidth. Therefore, the CPU simulation in the next window will continue with the same memory latency: $Latency_{i+1} = Latency_i$.

Otherwise, a difference between $cpuBW_i$ and $messBW_i$ suggests inconsistent simulated memory latency and bandwidth. This can happen, for example, if the application changes its behavior. Figure 8 illustrates the case in which the application increases the frequency of memory request leading to the higher bandwidth: $cpuBW_i > messBW_i$ ❹. In this case, the simulated memory bandwidth $cpuBW_i$ does not correspond to the memory $Latency_i$ used in the CPU simulation. To address this inconsistency, the Mess simulator adjusts the predicted application position in the bandwidth–latency curves. The objective of this adjustment is not to reach the correct $(BW, Latency)$ position in a single iteration. The next Mess estimate, $(messBW_{i+1}, Latency_{i+1})$, will be positioned in-between $messBW_i$ and $cpuBW_i$ ❺. The exact position is determined based on the user-defined convergence factor: $messBW_{i+1} = messBW_i + convFactor \times (cpuBW_i - messBW_i)$. The approach is based on the proportional–integral controller mechanism from the control theory [77], [78]. Finally,

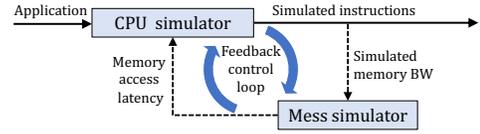


Fig. 7. Mess simulator uses a feedback control loop to adjust the simulated memory access latency.

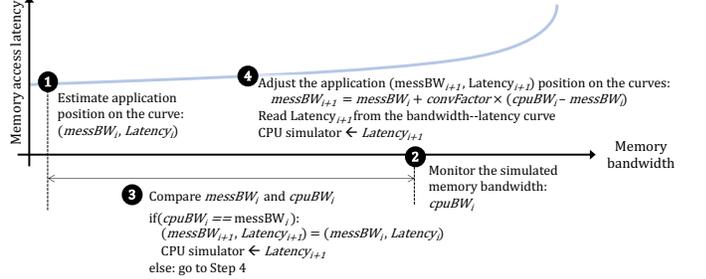


Fig. 8. One control loop iteration: Mess simulator monitors the simulated memory bandwidth, $cpuBW_i$, and compares it with the $messBW_i$ estimated at the beginning of the simulation window. If a major difference is detected, the Mess simulator adjusts the application position in the bandwidth–latency curves.

the Mess uses $messBW_{i+1}$ to read the $Latency_{i+1}$ from the corresponding bandwidth–latency memory curve. The next simulation window starts with the Mess simulator providing memory access $Latency_{i+1}$ to the CPU simulator.

B. Evaluation

We evaluate the Mess simulator integrated with ZSim and gem5 against the actual hardware. We compare the simulated and actual bandwidth–latency curves as well as the performance of memory-bound benchmarks: STREAM [5], LMBench [8], and Google multichase [9].

1) *ZSim*: Figure 9 shows the DDR4, DDR5 and HBM2 bandwidth–latency curves measured with the ZSim connected to the Mess simulator.⁵ The configurations of the simulators match the actual Intel Skylake with 24-core and six DDR4-2666 memory channels. The simulated Mess curves, depicted in Figure 9(a), closely resemble the actual memory systems behavior (Figure 3(a)). The simulation error of the unloaded memory latency is below 1%, and it is around 3% for the maximum latencies. The difference between the simulated and the actual saturated bandwidth range is only 2%. Figures 9(b) and 9(c) show the ZSim+Mess simulation results for the high-end DDR5 and HBM memories. To saturate the 8-channel DDR5-4800 and 32-channel HBM2, we increase the number of simulated cores to 58 and 192, respectively. Again, the simulated bandwidth–latency curves closely resemble the performance of the corresponding actual memory systems (Figures 3(g) and 3(e)).

⁵Mess simulator also supports the Intel Optane technology. Optane’s bandwidth–latency curves are measured on a 16-core Cascade Lake server with 6×DDR4-2666 16 GB and 2×Intel Optane 128 GB memory in App Direct mode. Since Intel Optane technology is discontinued since 2023, we do not analyze its performance characteristics and simulation.

Figure 10 shows the evaluation results, w.r.t. to the actual Intel Skylake server, of all six ZSim memory models when running memory intensive STREAM [5], LMBench [8] and Google multichase [9]. The simulation errors are closely correlated with the similarity between the simulated and actual bandwidth–latency curves. The Mess shows the best accuracy with only 1.3% average error, followed by the M/D/1 and internal DDR model. The fixed-latency simulation and Ramulator show the highest errors of more than 80%. The Mess simulator is also fast. It increases the simulation time by only 26% higher w.r.t. a simple fixed-latency memory, and it is 2% and 15% faster than the M/D/1 and internal DDR model. The ZSim+Mess simulation speed-up over the ZSim+Ramulator and ZSim+DRAMsim3 is 13× and 15×.

2) *gem5*: Figure 11 shows the DDR5 and HBM2 bandwidth–latency curves simulated with the *gem5* connected to the Mess memory simulator. In all experiments, the *gem5* is configured to model Graviton3 cores [59] described in Section II-E1. To reduce simulation time, we simulate 16 CPU cores connected to a single memory channel.⁶ The simulated bandwidth–latency curves, when scaled to eight DDR5 channels or 32 HBM2 channels, closely resemble actual system behavior (Figures 3(e) and 3(g)).

We also evaluate the Mess memory simulation against the *gem5*'s built-in simple memory model and internal DDR5 model when running STREAM, LMBench, and Google Multichase benchmarks. In these experiments we simulate a whole server comprising 64 Graviton 3 cores and 8×DDR5-4800, and compare the results against the benchmark executions on the actual server. The results are presented in Figure 12. The Mess simulator decreases the average error from 30% (*gem5* simple memory model) and 15% (internal DDR5 model) to only 3%. Such a low error is unprecedented in any prior validation attempts [79]–[82]. Moreover, the *gem5* with Mess simulator reduces the simulation time by 1.6% w.r.t. to much simpler built-in memory models.

C. Simulation of novel memory systems: CXL memory expanders

The memory system complexity and the scarcity of publicly-available information often result in a considerable gap between a technology release and the support for its detailed hardware simulation. For example, public memory simulators started to support the DDR5 in 2023 [23], three years after production servers with DDR5 DIMMs hit the market.

The Mess simulator provides a fundamental solution for this gap because it can simulate emerging memory systems as soon as their bandwidth–latency curves are available. For memory technologies available on the market the curves can be measured on a real platform. For emerging memory devices that are not yet available in off-the-shelf servers, the bandwidth–latency curve can be measured on a developer board with a prototype of

⁶Simulation of a whole server comprising 64 Graviton 3 cores and 8×DDR5-4800 requires more than five hours to obtain a single bandwidth–latency datapoint. The full simulation of the bandwidth–latency curves would require more than a year.

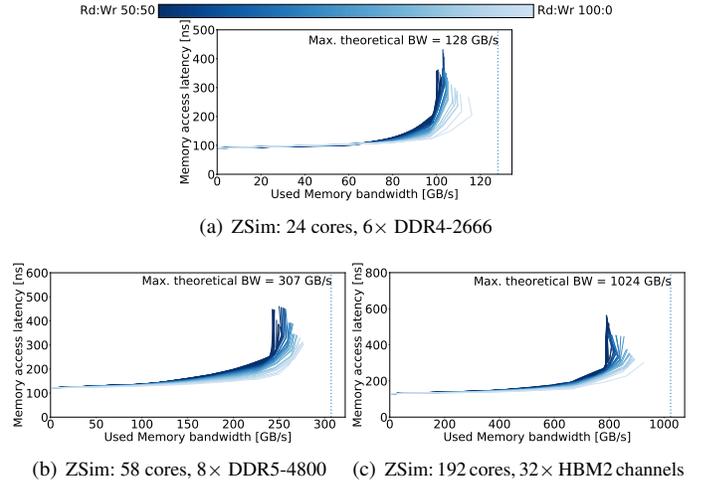


Fig. 9. ZSim with the Mess simulator closely matches the actual memory systems.

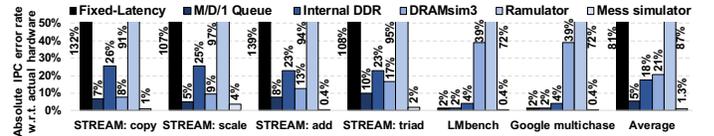


Fig. 10. The ZSim+Mess simulation error for STREAM, LMBench and Google multichase is only 1.3%.

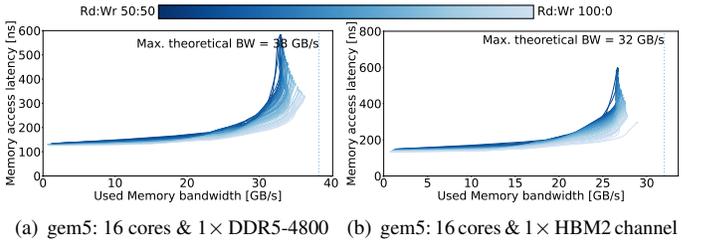


Fig. 11. *gem5* with the Mess simulator, when scaled, closely follows the actual memory system curves (Figures 3(e) and 3(g)).

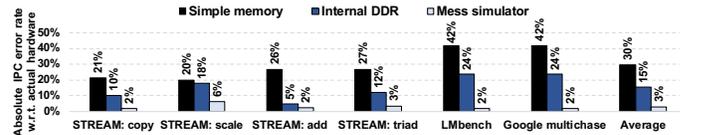


Fig. 12. The *gem5*+Mess simulation error for STREAM, LMBench and Google multichase is only 3%.

the new device, or alternatively it can be provided by the manufacturers, e.g. based on their detailed proprietary RTL models.

We will demonstrate the Mess simulation of novel memory systems with an example of the Compute Express Link (CXL) memory expanders. CXL is an emerging interconnect standard for processors, accelerators and memory devices. The CXL memory expanders enable a straightforward enlargement of the memory system capacity and bandwidth, as well as the exploration of unconventional disaggregated memory systems [33]. One of the main limitations for an academic research in this

field, however, is the lack of reliable performance models for these devices.

The Mess simulation is performed with the CXL memory expanders bandwidth–latency curves provided by Micron Technology based on their detailed hardware model. In particular, we model a CXL memory expander connected to the host via the CXL 2.0 PCIe 5.0 interface with 1×8 Lanes. The device comprises one memory controller connected to a DDR5-5600 DIMM with two ranks. All the CXL modules, Front end, Central controller and Memory controller, are implemented in SystemC. The modules communicate by using the manufacturer’s proprietary Transaction Level Modeling (TLM) framework, which is based on SystemC TLM [83].

The obtained bandwidth–latency curves are shown in Figure 13(a). The figure plots the round-trip latency from the CXL host input pins. To consider a full load-to-use latency, a user should add the round-trip time between the CPU core and the CXL host. We measure this latency component with the Intel MLC [11]. The CXL memory expanders show a similar performance trends as the DDRx or HBM memory systems: latency that increases with the system load, significant non-linear increase after a saturation point, and the impact of the traffic read/write ratio. One major difference is that the CXL interface provides the best performance for a balanced reads and writes traffic, while its performance drops significantly for the 100%-read or 100%-write traffic. This is because, unlike the DDRx interfaces, CXL is a full-duplex interconnect with independent read and write links. Therefore, the CXL can transmit simultaneously in both directions, but in the case of the unbalanced traffic one CXL transmission direction could be saturated while other direction is negligibly used.

We use the obtained CXL memory bandwidth–latency curves in the Mess simulator integrated with ZSim, gem5 and OpenPiton Metro-MPI simulators (see Figure 13). To reduce long OpenPiton Metro-MPI simulation time, we model only 25 curves with a small number of experimental points in each curve. For this reason some segments of the curves are discrete. Nevertheless, the OpenPiton Metro-MPI simulations match the general trend and the saturated bandwidth range of the manufacturer’s curves. The maximum latency range is below the manufacturers CXL curves because the simulated small in-order Ariane cores with only 2-entry MSHRs cannot saturate the target memory system. This behavior is already detected and discussed in Section II-E3. ZSim and gem5 results practically match the manufacturer’s CXL curves. In Appendix B, we compare our CXL simulation platform against prior approach to emulate memory-over-CXL.

IV. MESS APPLICATION PROFILING

The Mess framework also enhances the memory-related application profiling. We demonstrate this functionality with the Mess extension of Exrae and Paraver, production HPC performance tools for detailed application tracing and analysis [35]. The Mess application profiling adds a new layer of information related to the application’s memory performance metrics. This information can be correlated with other application runtime

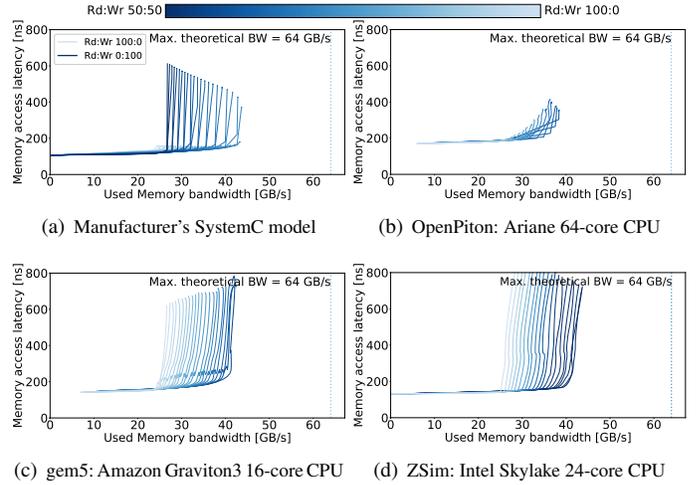


Fig. 13. Bandwidth–latency curves of the CXL memory expander. Mess simulator closely follows the Manufacturer’s SystemC model.

activities and the source code, leading to a better overall understanding of the application’s characteristics and behavior.

A. Background: Exrae and Paraver

Paraver is a flexible data browser for application performance analysis [84], [85]. It can display and analyze application MPI calls, duration of the computing phases, values of the hardware counters, etc. Paraver can also summarize application behavior in histograms and link it with the corresponding source code. The input data format for Paraver is a timestamped trace of events, states and communications [86]. For parallel applications, the traces are usually generated with the Exrae tool [87].

Exrae automatically collects entry and exit call points to the programming model runtime, source code references, hardware counters metrics, dynamic memory allocation, I/O system calls, and user functions. It is compatible with programs written in C, Fortran, Java, Python, and combinations of different languages, and it supports a wide range of parallel programming models. Exrae is available for most UNIX-based operating systems and it is deployed in all relevant HPC architectures, including CPU-based systems and accelerators.

B. Use cases

We illustrate the capabilities of the Mess application profiling with an example of the memory-intensive HPCG benchmark [7], [88] running in a dual-socket Cascade Lake server (Table I). We fully utilize the one CPU socket by executing 16 benchmark copies, one on each core. Exrae monitors the application memory behavior with a dedicated profiling process which traces the memory bandwidth counters. The sampling frequency is configurable, and it is 10 ms by default. Even with this fine-grain profiling, the introduced overhead is negligible, below 1%.

The extended Paraver tool correlates the application memory bandwidth measurements with Mess memory curves. The application measurements are plotted on the curves as a set of points, each of them corresponding to 10 ms of the application

runtime. The application memory use can be also incorporated into the Paraver trace file, so a user can analyze its evolution over time, and correlate it with other application’s behavior and the source code.

1) *Bandwidth–latency curves*: Figure 14 depicts the Mess memory-related profile of the HPCG benchmark. Most of the HPCG execution is located in the saturated bandwidth area, above 75 GB/s. Sporadically, the benchmark even reaches the maximum sustained bandwidth with peak memory latencies in the range of 260–290 ns. Also, each HPCG point on the curves is associated with a memory stress score. The score value ranges from 0, for the unloaded memory system, to 1, corresponding to the right-most area of the bandwidth–latency curves. Memory stress score in a given point is calculated as a weighted sum of two parameters, the memory latency and the curve inclination. The latency itself is a good proxy of the system stress, while the inclination shows the memory system sensitivity to a bandwidth change. Gentle inclination indicates that a memory bandwidth change would have a minor impact on the memory access latency and the overall performance. In the steep curve segments, e.g. 95–100 GB/s area in Figure 14, small bandwidth changes can rapidly saturate the memory system leading to a major latency increase. The Mess extension of Paraver already includes the stress score visualization with a green–yellow–red gradient that can be easily interpreted by application developers.

2) *Timeline analysis*: Once the memory stress score is incorporated into the application’s Paraver trace, it can be combined with other aspects of the application analysis, as illustrated in Figure 15. The figure analyzes around two seconds of the HPCG runtime, from 241,748,818 μs to 243,728,242 μs (x -axis). Guided by the sequence of MPI calls illustrated in Figure 15 (top), we identify the application’s main iterative loop and, using MPI_Allreduce (pink) as delimiter, we select two iterations to focus the analysis on the compute phases (Figure 15, middle). The color gradient corresponds to the length of the compute phase: green to blue gradient for short to long phases. Figure 15 (bottom) shows the memory stress score for this region. The longest compute phases (blue) exhibits two distinct memory pressure behaviors: at the start of the phase, the memory stress score rises to 0.71, and then halfway through the phase it decreases to 0.64. The fine-grain application profiling can detect different memory stress score values even within a single compute phase.

3) *Links to the source code*: Extrae also collects callstack information of the MPI calls, referred to as the MPI call-points,⁷ which are used to link the application runtime behavior with the source code. With the Mess application-profiling extension of Paraver, the application source code can be linked to its memory-related behavior. This is fundamental for making data placement decisions in heterogeneous memory systems, e.g. comprising DDRx DIMMs and HBM devices [89], [90].

⁷A callpoint refers to the file and line number where the program initiates an MPI call at a given level of the callstack, typically the last one. This point serves as a boundary for a region that begins with the current MPI call and extends until the next one. In the tables, we indicate the starting callpoint.

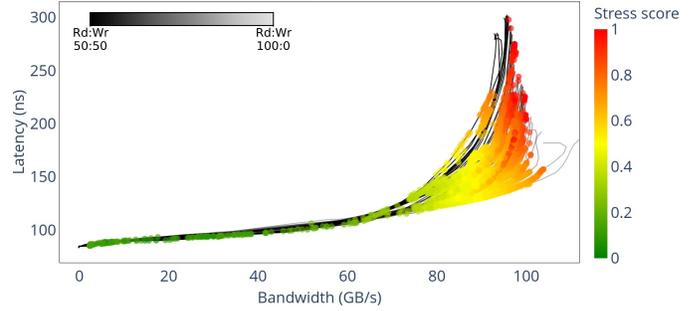


Fig. 14. Most of the HPCG execution is located in the saturated bandwidth area, above 75 GB/s. The Mess application-profiling extension of Paraver already includes the memory stress score visualization with a green–yellow–red gradient.

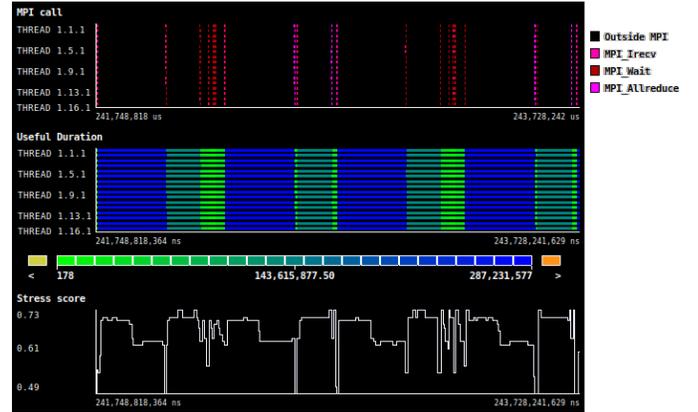


Fig. 15. Timeline showing two iterations of the HPCG benchmark with MPI calls (top), computations duration (middle) and memory stress score (bottom).

V. RELATED WORK

Mess framework provides a unified view of the memory system performance that covers the memory benchmarking, simulation and application profiling. Although these three memory performance aspects are inherently interrelated, they are currently analyzed with distinct and decoupled tools.

A. Memory system benchmarks

Memory access latency and utilized bandwidth are commonly treated as independent concepts measured by separate memory benchmarks. Lmbench [8] and Google Multichase [9] measure the load-to-use latency in an unloaded memory system, while STREAM [5], [66], STREAM2 [91], Hopscotch [92], CAMP [6], and HPCG [7], [88] measure the maximum obtainable memory bandwidth or performance of the application kernels that are proportional to it. Only recently the community started to make the first steps in measuring latencies in loaded memory systems. The Intel Memory Latency Checker (MLC) tool [11] is used to show how memory access latency increases for higher used memory bandwidths [27], [37] and to compare systems based on fundamentally different memory technologies, such as the DRAM and Optane [38]. X-Mem benchmark [12] reports loaded access latencies for cache subsystem, main memory, and NUMA memory nodes. The impact of the read

and write traffic to the memory system performance is not measured nor analyzed. Overall, current memory systems benchmarks provide a small number of data points in a very large and complex memory-performance space.

The Mess benchmark is designed for holistic close-to-the-hardware memory system performance characterization that is easily adaptive to different target platforms. It significantly increases the coverage and the level of detail of the previous tools, leading to new findings in memory behavior of the hardware platforms and simulators under study.

B. Memory system simulation

The Mess framework tightly integrates the memory performance characterization into the memory simulation. We compare the Mess simulator with the state-of-the-art memory models included in the CPU simulators [13], [14], [18], [46], [73]–[75], [80], [81] as well as the external cycle-accurate memory simulators [22], [24]. The Mess memory simulator is fast, accurate and easily-integrated with the CPU simulators. It can support novel memory systems as soon as their detailed bandwidth–latency curves are measured on actual production systems or prototypes, or provided by the manufacturers. Therefore, Mess can simulate high-end and future memory systems much sooner than the standard memory simulators which consider detailed memory device sequences and timings [20]–[25]. Mess is the first memory simulator to support CXL memory expanders.

Apart from the hardware simulation, system performance can be analyzed with analytical models. The PROFET model [53] and Interval model [93] predict memory system impact on the overall application performance. The predictions are based on the application runtime profiling combined with an analytical performance model. The main objective is to provide an alternative to complex and slow CPU simulations. This is orthogonal and complementary to the Mess simulator that targets the main memory simulation.

C. Application profiling

ProfileMe [26] and PerfMemPlus [27] determine whether the application is memory bound based on its memory access latency, measured with the Intel’s Event Based Sampling (PEBS) [28]. The Roofline model [29], [30] analyzes compute performance and memory bandwidth. The application is classified as compute or memory bound based on the comparison with the performance roofs of the target hardware platform. The Top-down model [31] analyzes the application CPI stack. The application is categorized as memory bound if its significant CPI component is caused by the main memory accesses. The model also distinguishes between the memory latency and bandwidth stalls depending on the occupancy of the memory controller queues. Below 70% occupancy, the stalls are considered latency-bound; above this threshold they are bandwidth-bound.

As a part of future work, we will synthesize the Mess application profiling with the Roofline and Top-down models.

The Mess and Roofline integration will connect the application memory bandwidth–latency analysis with its compute performance. The Top-down model will provide the CPI stack. Also, the Top-down distinction between the memory latency and bandwidth stalls will be enhanced with the Mess detailed bandwidth–latency analysis.

VI. CONCLUSIONS

The **Memory stress (Mess) framework** offers a comprehensive and unified approach to memory system benchmarking, simulation, and application profiling. It is publicly-released and ready to be used by the community for better understanding of the current and exploration of future memory systems.

The **Mess benchmark** provides a detailed and holistic and memory systems performance view represented by a family of bandwidth–latency curves. The current Mess benchmark release covers x86, ARM, Power, RISC-V, and NVIDIA’s PTX ISAs, and we used it to characterize servers from Intel, AMD, IBM, Fujitsu, Amazon, and NVIDIA with DDR4, DDR5, HBM2, and HBM2E main memory. The Mess characterization significantly expands coverage of the existing tools, uncovering new insights into the memory systems performance and behavior. We also used Mess to benchmark established publicly-available memory models and simulators. Our detailed evaluation shows that the existing memory models poorly resemble the actual system performance, leading to high error rates when simulating memory intensive workloads.

The **Mess memory simulator** couples memory simulation to memory performance benchmarking and predicts the memory access latencies based on the application position on the bandwidth–latency curves. A memory system can be, therefore, simulated as soon as its bandwidth–latency curves are available, which removes the current lag between the emergence of memory technologies and development of the reliable simulation models. The Mess simulator closely matches the actual memory systems performance and it shows an unprecedented low error of 0.4–6% when simulating widely-used memory benchmarks. It is also fast and reduces the simulation time of cycle-accurate memory simulators by 13–15×. The Mess simulator is easily integrated with ZSim, gem5, and OpenPiton Metro-MPI CPU simulators and it supports a wide range of memory systems based on DDR4, DDR5, Optane, HBM2, HBM2E and CXL memory expanders.

The **Mess application profiling** determines application position on the corresponding memory bandwidth–latency curves. This information, correlated with other runtime activities and source code, enhances overall understanding of application behavior. The integration of Mess application profiling into a suite of production HPC performance analysis tools further enhances its utility and accessibility.

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APPENDIX

A. Mess benchmark implementation

In this appendix, we discuss Mess benchmark implementation. It includes implementation of pointer-chase and traffic generator. The scripts and manuals for the experimental setup, execution and measurements is included in the public Mess repository. The measurements post-processing removes the outliers, mitigates the noise and plots the results.

1) *Pointer-chase*: The pointer-chase contains a sequence of dependent back-to-back load instructions that access the main memory. Since the instructions are dependent, their execution is serialized, so the average memory access latency is calculated as the ratio between the total execution time and the number of instructions executed. This is guaranteed by the pointer-chase design. In the benchmark initialization, we allocate a contiguous section of memory and initialize it in such a way that a given array element contains the address of the next array element (memory location) that we want to access. This ensures the dependency between the consecutive load instructions. To force accesses to the main memory (and not on-chip caches), the pointer-chase traverses the whole array whose size exceeds the last-level cache. To avoid any cache-line spatial locality, each array element occupies the whole cache line (64 Byte). Finally, to diminish the impact of data prefetching and temporal locality during traversing, the pointer-chase traverses the array in a random pattern. The pointer-chase source code is detailed in Listing 1:

Listing 1

POINTER-CHASE SOURCE CODE. X86 ASSEMBLY. IN OUR STUDY WE ALSO USE THE BENCHMARK FOR THE ARM, IBM POWER, AND RISC-V ISA.

Line	Source code	Explanation
0001	register struct line *next asm("rax");	struct line owns pointer to the next access
0002	register int i asm("ecx");	ecx is the loop counter
0003	i = 1000000;	initialization of the loop counter. C format
0004	next = ptr->next	first memory access in C format
0005	start_loop:	beginning of the loop
0006	mov(%rax), %rax	load instruction (pointer-chase)
0007	mov(%rax), %rax	load instruction (pointer-chase)
...
1007	mov(%rax), %rax	load instruction (pointer-chase)
1008	dec %ecx	decrement loop counter
1009	jnz start_loop	if counter is not zero jump to start of the loop

- Lines 0001–0004 initialize the benchmark: set the number of load instructions, initialize the registers, etc.
- Lines 0006–1007 are the core of the benchmark. They are a series of back-to-back load instructions for traversing the array. Each load instruction has data dependency on the previous one, so their execution is serialized.
- Line 1008 decrements the loop counter.
- Line 1009 checks the loop exit condition.

2) *Traffic generator*: We write the core of the memory traffic generator directly in assembly. This enables the development of more precise code (changes at the level of the assembly instruction) and prevents any system software optimizations (e.g. compiler optimizations). The benchmark generates different read and write memory traffic by executing a different mix of load and store instructions in the source code, each of them in a separate assembly file. In the current implementation, the benchmark can execute from 100% load to 100% store operations, with a step of 2%.⁸ The generated memory bandwidth is adjusted the issue rate of the memory operations. This is done by interleaving the load/store operation sequence with a configurable dummy loop of `nop` operations. To reduce the overhead of the loop management, loop counter decrement and jump operations, we employ a long loop of around 100 load/store operations. Listings 2, and 3 show the memory traffic generator implementation in the x86 ISA. The benchmark is also available for ARM, IBM Power, and RISC-V ISAs.

- Lines 001–008 initialize the benchmark:
 - Lines 001–002 loads the addresses of the arrays `a` and `c` into the registers.
 - Lines 003–004 initialize a register as the loop counter.
 - Lines 005–006 set the size of the array `a` and `c`.
 - Lines 007–008 set the iteration of the dummy `nop` function. This controls the rate of the memory operations, i.e. used memory bandwidth.

⁸The ratio of loads and stores executed by the benchmark does not lead to the same ratio of the reads and writes in the memory traffic. This is because most of the state-of-the-art HPC servers deploy a write-allocate cache policy. With this policy each store operation targeting data in main memory is first read into the cache (memory read), then modified, and finally written to the main memory once the cache line is evicted. Since each store operation causes one memory read and one memory write, e.g. 100% store kernel causes 50%-read 50%-write memory traffic.

Listing 2

MEMORY TRAFFIC GENERATOR, x86 ISA. DIFFERENT READ AND WRITE MEMORY TRAFFIC IS GENERATED BY EXECUTING A DIFFERENT MIX OF LOAD AND STORE INSTRUCTIONS IN THE SOURCE CODE, EACH OF THEM IN A SEPARATE ASSEMBLY FILE. THE GENERATED MEMORY BANDWIDTH IS ADJUSTED THE ISSUE RATE OF THE MEMORY OPERATIONS. THIS IS DONE BY INTERLEAVING THE LOAD/STORE OPERATION SEQUENCE WITH A CONFIGURABLE DUMMY LOOP OF NOP OPERATIONS.

Line	Source code	Explanation
001	register double *a asm("r10");	load array a address into the register r10
002	register double *c asm("r11");	load array c address into the register r11
003	register ssize_t i asm("rbx");	register rbx holds the loop counter
004	i = 0;	initialize the counter (i) by 0
005	register ssize_t n asm("r12");	r12 holds the size of the arrays
006	n = *array_size;	load r12 with size of the arrays
007	register int *p asm("r15");	register r15 holds the nopCount value
008	p = nopCount;	load r15 with value of nopCount
009	..L_50:	the beginning of the kernel loop
010	vmovupd (%r10,%rbx,8), %ymm0;	load instruction
011	vmovupd %ymm1, (%r11,%rbx,8);	store instruction
012	vmovupd 32(%r10,%rbx,8), %ymm0;	load instruction
013	vmovupd %ymm1, 32(%r11,%rbx,8);	store instruction
014	vmovupd 64(%r10,%rbx,8), %ymm0;	load instruction
015	vmovupd %ymm1, 64(%r11,%rbx,8);	store instruction
016	movq %r15, %rdi;	send number of nopCount as an input of nop function
017	call nop;	call nop function
...
138	vmovupd 1536(%r10,%rbx,8), %ymm0;	load instruction
139	vmovupd %ymm1, 1536(%r11,%rbx,8);	store instruction
140	vmovupd 1568(%r10,%rbx,8), %ymm0;	load instruction
141	vmovupd %ymm1, 1568(%r11,%rbx,8);	store instruction
142	movq %r15, %rdi;	send number of nopCount as an input of nop function
143	call nop;	call nop function
144	add \$200, %rbx;	increment the loop counter
145	cmp %r12, %rbx;	check the exit condition
146	jb ..L_50;	conditional jump to beginning of the kernel loop

- The main loop of the kernel starts at line 009. The loop comprises a series of load and store instructions (Lines 010–015) followed by the call to the dummy nop function (Lines 016–017).

– The nop function is shown in Listing 3. The number of nop operations is configurable: the larger the number of nop operations in each function call, the lower the rate of memory instruction, and therefore the lower used memory bandwidth. This configuration is managed by the value of nopCount parameter. When nopCount parameter is set to 0, i=0 in Listing 3, the function is finalized without entering the nop loop. This causes only a negligible halt in the load and store sequence, leading to the maximum pressure to the memory system. As we increase the value of the nopCount parameter, we increase the number of the iterations in the dummy nop loop, and therefore reduce the rate of the memory operations issued by the memory traffic generator.

- The sequence of interleaved load and store instructions, and calls to the nop function is repeated until the line 143. This is the core of the benchmark. In the current implementation, each iteration of the main loop comprises 100 load and store instructions.
- Lines 144–146 finalize the loop iteration: increment the loop counter, check the exit condition, and conditionally jump to the beginning of the loop.

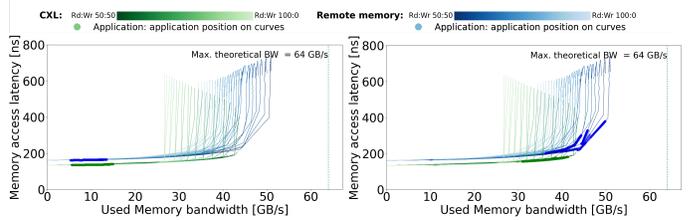
B. Case study: Remote-socket memory emulation of CXL memory expanders

Recent industrial studies emulate CXL memory expansion in cloud and datacenter servers with conventional dual-socket

Listing 3

DUMMY NOP FUNCTION IS USED TO GENERATE A PAUSE IN THE SEQUENCE OF THE LOAD AND STORE INSTRUCTIONS IN THE MEMORY TRAFFIC GENERATOR (SEE LISTING 2). THE INPUT PARAMETER NOPCOUNT IS THE NUMBER OF THE DUMMY LOOP ITERATIONS. THE LARGER THE NUMBER OF ITERATIONS, THE LOWER THE RATE OF MEMORY INSTRUCTION AND THE LOWER THE GENERATED MEMORY BANDWIDTH.

Line	Source code	Explanation
001	int nop(int *nopCount) {	definition of nop function
002	unsigned int i = *nopCount;	i is the loop counter; number of loops for nop operations
003	if (!i) {	if i is zero then return immediately
004	return 0;	
005	} else {	assembly section of nop function
006	asm(it is written in extended assembly format
007	mov %0, %%ecx;	move the value of %0 register into ecx register
008	the_loop%=:	the beginning of the loop
009	nop;	nop instruction
010	dec %%ecx	decrementing the counter
011	jnz the_loop%=	conditional jump to beginning of the loop
012	: "r" (i) : ecx	put the value of i into register %0 (extended assembly)
013);	
014	return 0;	
015	}	



(a) The perlbench experiences higher remote-memory latency which leads to memory bandwidth which leads to 11% lower performance. (b) The lbm reaches higher remote-memory latency which leads to memory bandwidth which leads to 5% higher performance.

Fig. 16. Remote-socket emulation of CXL memory expanders: Bandwidth–latency curves and implications

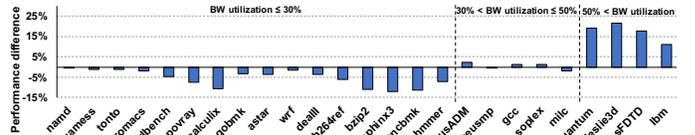


Fig. 17. Remote-socket memory emulation of CXL memory expanders: Application performance difference is correlated with its bandwidth utilization. SPEC2006 benchmarks, 24-core Intel Skylake CPU.

systems: one socket is used as a host CPU and the other socket as a CPU-less memory expander [94], [95]. To evaluate this approach, we perform a detailed simulation of both systems. The CPU host is simulated with the ZSim configured to model the Intel 24-core Skylake processor (Section II-E2). We use Micron Technology’s bandwidth–latency curves to model the CXL memory expander, and measurements from the actual dual-socket server to model the remote-socket memory. In each system configuration, we simulate 500 billion instructions of the multiprogrammed SPEC CPU2006 workloads [41].

Figure 16 plots the CXL (green) and remote-socket (blue) memory curves, and the benchmark behavior. Each 20,000 simulated instructions we monitor the benchmark read and write memory bandwidth, and then plot each observation as a point on the corresponding bandwidth–latency curve. The figure shows two characteristic use-cases. The perlbench benchmark

(Figure 16(a)) has a low bandwidth utilization. In this area remote-socket memory curves shows approximately 28 ns higher latency, which leads to somewhat lower performance w.r.t. target CXL system. We detect the opposite behavior for high-bandwidth benchmarks. The remote-socket curves have a higher bandwidth saturation area. This leads to higher achieved bandwidths and the overall performance of the bandwidth-intensive benchmarks, such as the lbm illustrated in Figure 16(b). The overall performance trend is illustrated in Figure 17. The figure plots the results for all SPEC CPU2006 benchmarks, sorted from the lowest to the highest bandwidth utilization. For low-bandwidth benchmarks, remote-socket emulation provides up to 12% lower performance w.r.t. to the target CXL system. Both system provide a similar performance for the benchmarks with medium bandwidth utilization between 30% and 50% of CXL max theoretical bandwidth. For the high-bandwidth benchmarks, the remote-socket memory provides 11%–22% higher performance.

To the best of our knowledge, this is the first study that enables a detailed simulation of CXL memory expanders based on the manufacturer’s SystemC model. The model is already integrated and publicly released with ZSim, gem5 and OpenPiton Metro-MPI simulators. We also provide the performance analysis and correction factors that can be useful for future studies who want to keep using remote-socket memory emulation, e.g. due to its much faster execution time.